

# **Excellent Integrated System Limited**

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Rohm Semiconductor 2SC5916TLQ

For any questions, you can email us directly: <u>sales@integrated-circuit.com</u>



•External dimensions (Units : mm)

Each lead has same dimensions

тѕмтз

(1) Base(2) Emitter(3) Collector

03

Abbreviated symbol : UY

Transistor

2SC5916

# Medium power transistor (30V, 2A) 2SC5916

#### Features

- 1) High speed switching. (Tf : Typ. : 20ns at Ic = 2A)
- 2) Low saturation voltage, typically
- (Typ.: 200mV at Ic = 1.0A, IB = 0.1A)
- 3) Strong discharge power for inductive load and capacitance load.
- 4) Complements the 2SA2113

#### Applications

Low frequency amplifier High speed switching

#### Structure

NPN Silicon epitaxial planar transistor

#### Packaging specifications

Туре	Package	Taping
	Code	TL
	Basic ordering unit (pieces)	3000
2SC5916		0

#### •Absolute maximum ratings (Ta=25°C)

	,		
Parameter	Symbol	Limits	Unit
Collector-base voltage	Vсво	30	V
Collector-emitter voltage	Vceo	30	V
Emitter-base voltage	Vево	6	V
Collector current	lc	2	А
	Іср	4	A *1
Power dissipation	Pc	500	mW <sup>*2</sup>
Junction temperature	Tj	150	°C
Range of storage temperature	Tstg	-55~+150	°C

\*1 Pw=10ms

\*2 Each terminal mounted on a recommended land.



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### Transistor

#### Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions	
Collector-base breakdown voltage	BVCEO	30	-	-	V	Ic=100μA	
Collector-emitter breakdown voltage	ВУсво	30	-	-	V	Ic=1mA	
Emitter-base breakdown voltage	ВVево	6	-	-	V	Ιε=100μΑ	
Collector cut-off current	Ісво	-	-	1.0	μΑ	Vcb=20V	
Emitter cut-off current	Іево	-	-	1.0	μΑ	VEB=4V	
Collector-emitter staturation voltage	VCE(sat)	-	200	400	mV	Іс=1.0А, Ів=0.1А	
DC current gain	hfe	120	-	390	-	Vcd=2V, Ic=100mA	
Transition frequency	fT	-	250	-	MHz	Vce=10V, Ie=-100mA, f=10MHz	
Collector output capacitance	Cob	-	15	-	pF	Vсв=10V, IE=0, f=1MHz	
Turn-on time	Ton	_	25	_	ns	Ic=2A IB1=200mA IB2=-200mA	
Storage time	Tstg	_	100	_	ns		
Fall time	Tf	_	20	_	ns	Vcc≑–25V	

#### **•**hfe RANK

Q	R		
120-270	180-390		

#### Electrical characteristic curves

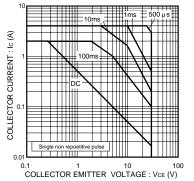
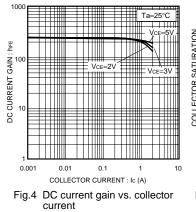


Fig.1 Safe operating area



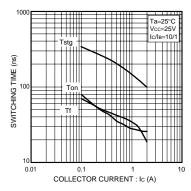
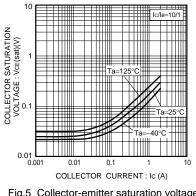
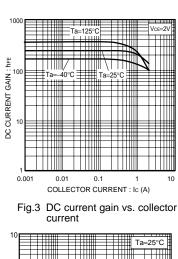
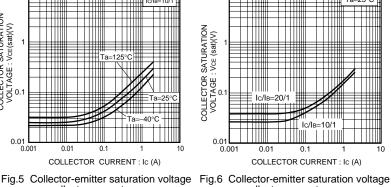


Fig.2 Switching Time



vs. collector current





vs. collector current





## Transistor

# 2SC5916

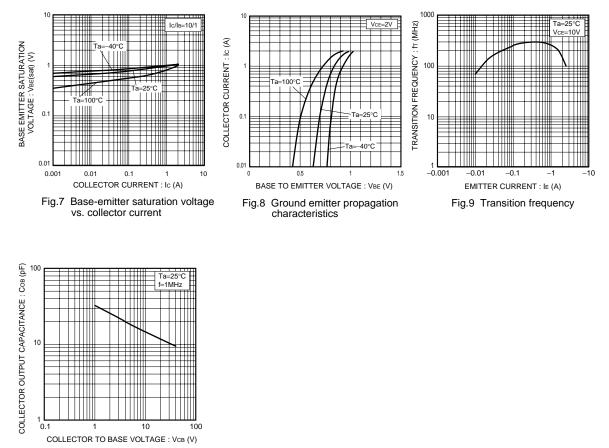
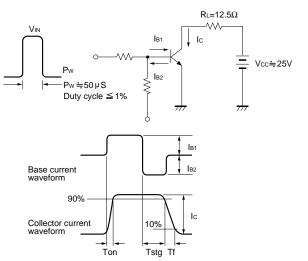


Fig.10 Collector output capacitance

#### •Switching characteristics measurement circuits







# Appendix

#### Notes

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